

ALPHANUMERIC INDEX — CROSS-REFERENCE (Continued)

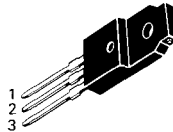
Industry Part Number	Motorola Direct Replacement	Motorola Similar Replacement	Page Number	Industry Part Number	Motorola Direct Replacement	Motorola Similar Replacement	Page Number
2N6410		MJE200	3-866	2N6531		TIP102	3-1091
2N6411		MJE210	3-866	2N6532		TIP102	3-1091
2N6412		MJE180	3-862	2N6534		2N6301	3-147
2N6413		MJE181	3-862	2N6535		TIP102	3-1091
2N6414		MJE170	3-862	2N6536		TIP102	3-1091
2N6415		MJE171	3-862	2N6542	2N6543		3-215
2N6416		MJE243	3-870	2N6543	2N6543		3-215
2N6417		MJE243	3-870	2N6544	2N6545		3-221
2N6418		MJE253	3-870	2N6545	2N6545		3-221
2N6419		MJE253	3-870	2N6546	2N6546		3-225
2N6420	2N6420		3-20	2N6546JAN	2N6546JAN		3-225
2N6421	2N6421		3-20	2N6546JTX	2N6546JTX		3-225
2N6422	2N6422		3-20	2N6547	2N6547		3-225
2N6423		2N6212	3-161	2N6547JAN	2N6547JAN		3-225
2N6424		2N6212	3-161	2N6547JTX	2N6547JTX		3-225
2N6425		2N6212	3-161	2N6548		MJE80C	3-888
2N6436	2N6436		3-203	2N6549		MJE80C	3-888
2N6437	2N6437		3-203	2N6551		2N4923	3-79
2N6437JAN	2N6437JAN		3-203	2N6552		2N4923	3-79
2N6437JTX	2N6437JTX		3-203	2N6553		2N4923	3-79
2N6437JTXV	2N6437JTXV		3-203	2N6554		2N4919	3-75
2N6438	2N6438		3-203	2N6555		2N4919	3-75
2N6438JAN	2N6438JAN		3-203	2N6556		2N4919	3-75
2N6438JTX	2N6438JTX		3-203	2N6557		MJE340	3-876
2N6438JTXV	2N6438JTXV		3-203	2N6558		MJE340	3-876
2N6465		MJE15030	3-972	2N6559		MJE340	3-876
2N6466		MJE15030	3-972	2N6569		2N3055	3-6
2N6467		MJE15031	3-972	2N6573		2N6546	3-225
2N6468		MJE15031	3-972	2N6574		2N6546	3-225
2N6469		2N5879	3-123	2N6575		2N6547	3-225
2N6470		2N5881	3-123	2N6576	2N6576		3-229
2N6471		2N5881	3-123	2N6577	2N6577		3-229
2N6472		2N5882	3-123	2N6578	2N6578		3-229
2N6473		MJE15028	3-972	2N6609	2N6609		3-52
2N6474		MJE15028	3-972	2N6648	2N6648		3-195
2N6475		MJE15029	3-972	2N6648JAN	2N6648JAN		3-195
2N6476		MJE15029	3-972	2N6648JTX	2N6648JTX		3-195
2N6477		MJE15028	3-972	2N6648JTXV	2N6648JTXV		3-195
2N6478		MJE15030	3-972	2N6649		2N6054	3-147
2N6486	2N6486		3-207	2N6649JAN	2N6649JAN		—
2N6487	2N6487		3-207	2N6649JTX	2N6649JTX		—
2N6488	2N6488		3-207	2N6649JTXV	2N6649JTXV		—
2N6489	2N6489		3-207	2N6650JAN	2N6650JAN		—
2N6490	2N6490		3-207	2N6650JTX	2N6650JTX		—
2N6491	2N6491		3-207	2N6650JTXV	2N6650JTXV		—
2N6492		2N6055	3-147	2N6666		2N6667	3-232
2N6493		2N6056	3-147	2N6667	2N6667		3-232
2N6494		2N6056	3-147	2N6668	2N6668		3-232
2N6495		2N5428	3-101	2N6671JAN	2N6671JAN		—
2N6496		2N6339	3-188	2N6671JTX	2N6671JTX		—
2N6497	2N6497		3-211	2N6671JTXV	2N6671JTXV		—
2N6498	2N6498		3-211	2N6673JAN	2N6673JAN		—
2N6499		MJE13005	3-944	2N6673JTX	2N6673JTX		—
2N6500		2N5430	3-101	2N6673JTXV	2N6673JTXV		—
2N6510		2N6306	3-181	2N6676		MJ16010	3-758
2N6511		2N6306	3-181	2N6677		MJ16010	3-758
2N6512		2N6545	3-221	2N6678		MJ16010	3-758
2N6513		2N6545	3-221	2N6833	2N6833		3-236
2N6514		2N6545	3-221	2N6834	2N6834		3-236
2N6530		TIP101	3-1091	2N6835	MJ16006		3-742

*Consult Motorola if a direct replacement is necessary.

TABLE 5 — PLASTIC TO-220 (continued)

I _C Cont Amps Max	V _{CEO} (sus) Volts Min	Device Type		h _{FE} Min/Max	@ I _C Amp	Resistive Switching			f _T MHz Min	P _D (Case) Watts @ 25°C
		NPN	PNP			t _s μs Max	t _f μs Max	@ I _C Amp		
10	60	D44H7	D45H7	20 min	4					50
		D44H8	D45H8	40 min	4					50
			D45H9	40 min	4					50
		MJE2801T		25/100	3					75
		MJE3055T	MJE2955T	20/70	4					75
		2N6387##	2N6667##	1k/20k	5				20#	65
		SE9300##	SE9400##	1k min	4				1#	70
	80	BDX33B##	BDX34B##	750 min	3				3	70
		BD809	BD810	15 min	4				1.5	90
		D44E3##		1000 min	5	2 typ	0.5 typ	10		50
			D45H12	40 min	4					50
		2N6388##	2N6668##	1k/20k	5				20#	65
		D44H10	D45H10	20 min	4	0.5 typ	0.14 typ	5	50 typ	50
12	300	D44H11	D45H11	40 min	4	0.5 typ	0.14 typ	5	50 typ	50
		SE9301##	SE9401##	1k min	4				1#	70
		BDX33C##	BDX34C##	750 min	3				3	70
		SE9302##	SE9402##	1k min	4				1#	70
		MJE13008		6/30	8	3	0.7	8	4	100
		MJE13009		6/30	8	3	0.7	8	4	100
	400	D44VH1	D45VH1	20 min	4	0.7	0.09	8	50 typ	83
		2N6486	2N6489	20/150	5	0.6 typ	0.3 typ	5	5	75
		BDW39	BDW44	1 k min	5	1 typ	1.5 typ	5	4	85
		D44VH4	D45VH4	20 min	4	0.5	0.09	8	50 typ	83
		2N6487	2N6490	20/150	5	0.6 typ	0.3 typ	5	5	75
		BDW40	BDW45	1 k min	5	1 typ	1.5 typ	5	4	85
15	60	D44VH7		20 min	4	0.5	0.09	8	50 typ	85
		2N6488	2N6491	20/150	5	0.6 typ	0.3 typ	5	5	75
		BDW41	BDW46	1 k min	5	1 typ	1.5 typ	5	4	85
		D44VH10	D45VH10	20 min	4	0.5	0.09	8	50 typ	83
		BDW42	BDW47	1 k min	5	1 typ	1.5 typ	5	4	85
		BDW43	BDW48	1 k min	5	1 typ	1.5 typ	5	4	85

|h_{FE}| @ 1 MHz, ## Darlington

TABLE 6 — PLASTIC Full Pak (TO-220 Type)

CASE 221C-02

I _C Cont Amps Max	V _{CEO} (sus) Volts Min	Device Type		h _{FE} Min/Max	@ I _C Amp	Resistive Switching			f _T MHz Min	P _D (Case) Watts @ 25°C
		NPN	PNP			t _s μs Max	t _f μs Max	@ I _C Amp		
1	250	MJF47		30/150	0.3	2 typ	0.17 typ	0.3	10	28
5	100	MJF122##	MJF127##	2000 min	3	1.5 typ	1.5 typ	3	4#	28
8	80		MJF6107	30/90	2	0.5 typ	0.13 typ	2	4	35
	100	MJF102##	MJF107##	3000 min	3	1.5 typ	1.5 typ	3	4#	35
	150	MJF15030	MJF15031	40 min	3	1 typ	0.15 typ	3	30	35
10	60	MJF3055	MJF2955	20/100	4				2	40

|h_{FE}| @ 1 MHz, ## Darlington

TABLE 12 — POWER DARLINGTONS (continued)

I _C Cont Amps Max	V _{CEO} (sus) Volts Min	Device Type		h _{FE} Min/Max	@ I _C Amp	Resistive Switching			h _{FE} @ 1 MHz Min	P _D (Case) Watts @ 25°C	Case JEDEC/MOT
		NPN	PNP			t _s μs Max	t _f μs Max	@ I _C Amp			
8	80	MJ1001	MJ901	1k min	3					90	TO-204/1
		TIP101	TIP106	1k/20k	3	1.5 typ	1.5 typ	3	4	80	TO-220/221A
		2N6044	2N6041	1k/10k	4	1.5 typ	1.5 typ	3	4	75	TO-220/221A
		2N6301	2N6299	750k/18k	4	1.5 typ	1.5 typ	4	4	75	TO-213A/80
		2N6056	2N6054	750k/18k	4	1.5 typ	1.5 typ	4	4	100	TO-204A/1
		MJE6044	MJE6041	1k/20k	4	1.5 typ	1.5 typ	4	2	75	TO-225AB/90
	100	BDX53C	BDX54C	750 min	3				4	60	TO-220/221A
		BD901	BD902	750 min	3				1	70	TO-220/221A
		MJE6045		1k/20k	4	1.5 typ	1.5 typ	4	2	75	TO-225AB/90
		MJD122	MJD127	1k/12k	4	1.5 typ	2 typ	4	4	20	TO-252/369A-04
		MJF102	MJF107	3k min	3	1.5 typ	1.5 typ	3	4	35	—/221C-02
		TIP102	TIP107	1k/20k	3	1.5 typ	1.5 typ	3	4	80	TO-220/221A
		2N6045	2N6042	1k/10k	4	1.5 typ	1.5 typ	3	4	75	TO-220/221A
	120	BDX53D	BDX54D	750 min	3				4	60	TO-220/221A
	150	BU807●		100 min	5	0.55 typ	0.2 typ	5		60	TO-220/221A
	200	BU806●		100 min	5	0.55 typ	0.2 typ	5		60	TO-220/221A
	300	MJE5740		200/400	4	8 typ	2 typ	6		80	TO-220/221A
	350	MJE5741		200/400	4	8 typ	2 typ	6		80	TO-220/221A
	400	MJE5742		200/400	4	8 typ	2 typ	6		80	TO-220/221A
	500	BUT50P●		30 min	2	0.75 typ	0.1 typ	5		100	TO-218/340D
	1400*	MJ10011		20 min	4			1	4	80	TO-204/1
10	40	2N6383	2N6648	1k/20k	5				20	100	TO-204/1
		D44E1		1000 min	5	2 typ	0.5 typ	10		50	TO-220/221A
	45	BDX33	BDX34	750 min	4				3	70	TO-220/221A
	60	BDV65	BDV64	1k min	5					125	TO-218/340D
		BDX33A	BDX34A	750 min	4				3	70	TO-220/221A
		MJ3000	MJ2500	1k min	5					150	TO-204/1
		2N6387	2N6667	1k/20k	5				20	65	TO-220/221A
		2N6384		1k/20k	5				20	100	TO-204/1
		D44E2		1000 min	5	2 typ	0.5 typ	10		50	TO-220/221A
		TIP140	TIP145	500 min	10	2.5 typ	2.5 typ	5	4	125	TO-218/340
	80	2N6388	2N6668	1k/20k	5				20	65	TO-220/221A
		2N6385		1k/20k	5				20	100	TO-204/1
		BDV65A	BDV64A	1k min	5					125	TO-218/340D
		BDX33B	BDX34B	750 min	3				3	70	TO-220/221A
		D44E3		1000 min	5	2 typ	0.5 typ	10		50	TO-220/221A
		MJD44E3		1k min	5	2 typ	0.5 typ	10		20	TO-252/369A-04
		TIP141	TIP146	500 min	10	2.5 typ	2.5 typ	5	4	125	TO-218/340
	100	BDV65B	BDV64B	1k min	5					125	TO-218/340D
		BDX33C	BDX34C	750 min	3				3	70	TO-220/221A
		TIP142	TIP147	500 min	10	2.5 typ	2.5 typ	5	4	125	TO-218/340
	120	BDV65C	BDV64C	1k min	5				3	125	TO-218/340D
		BDX33D	BDX34D	750 min	3					70	TO-220/221A
	200	BU323P		150 min	6	15	15	6		125	TO-218/340D
	250	BU323AP		150 min	6	15	15	6		125	TO-218/340D
	350	BU323		150 min	6	7.5 typ	5.2 typ	6		175	TO-204/1
		MJ10002		30/300	5	2.5	1	5	10	150	TO-204/1
		MJ10006●		30/300	5	1.5	0.5	5	10	150	TO-204/1
	400	BU323A		150 min	6	7.5 typ	5.2 typ	6		175	TO-204/1
		MJH10012		100/2k	6	15	15	6		118	TO-218/340
		MJ10007●		30/300	5	1.5	0.5	5	10	150	TO-204/1

● Darlington with speed-up diode.

(continued)

2N6609
See Page 3-52
2N6648
See Page 3-195

Darlington Silicon Power Transistors

... designed for general-purpose amplifier and low speed switching applications.

- High DC Current Gain — $h_{FE} = 3500$ (Typ) @ $I_C = 4$ Adc
- Collector-Emitter Sustaining Voltage — @ 200 mAdc
 $V_{CE(sus)} = 60$ Vdc (Min) — 2N6667
 $= 80$ Vdc (Min) — 2N6668
- Low Collector-Emitter Saturation Voltage — $V_{CE(sat)} = 2$ Vdc (Max) @ $I_C = 5$ Adc
- Monolithic Construction with Built-In Base-Emitter Shunt Resistors
- TO-220AB Compact Package
- Complementary to 2N6387, 2N6388

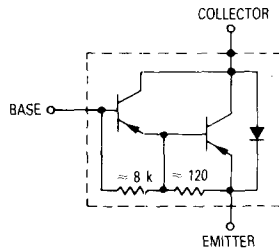
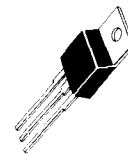


Figure 1. Darlington Schematic

2N6667
2N6668

PNP SILICON
DARLINGTON
POWER TRANSISTORS

10 AMPERES
60-80 VOLTS
65 WATTS



CASE 221A-04
TO-220AB

*MAXIMUM RATINGS

Rating	Symbol	2N6667	2N6668	Unit
Collector-Emitter Voltage	V_{CEO}	60	80	Vdc
Collector-Base Voltage	V_{CB}	60	80	Vdc
Emitter-Base Voltage	V_{EB}	5		Vdc
Collector Current — Continuous	I_C	10		Adc
— Peak		15		
Base Current	I_B	250		mAdc
Total Device Dissipation (at $T_C = 25^\circ\text{C}$ Derate above 25°C)	P_D	65 0.52		watts $W/^\circ\text{C}$
Total Device Dissipation (at $T_A = 25^\circ\text{C}$ Derate above 25°C)	P_D	2 0.016		Watts $W/^\circ\text{C}$
Operating and Storage Junction Temperature Range	T_J, T_{stg}	- 65 to + 150		$^\circ\text{C}$

THERMAL CHARACTERISTICS

Characteristics	Symbol	Max	Unit
Thermal Resistance, Junction to Case	$R_{\theta JC}$	1.92	$^\circ\text{C/W}$
Thermal Resistance, Junction to Ambient	$R_{\theta JA}$	62.5	$^\circ\text{C/W}$

* Indicates JEDEC Registered Data

2N6667, 2N6668

*ELECTRICAL CHARACTERISTICS (T_C = 25°C unless otherwise noted)

Characteristic		Symbol	Min	Max	Unit
OFF CHARACTERISTICS					
Collector-Emitter Sustaining Voltage (1) (I _C = 200 mAdc, I _B = 0)	2N6667 2N6668	V _{CEO(sus)}	60 80	— —	Vdc
Collector Cutoff Current (V _{CE} = 60 Vdc, I _B = 0) (V _{CE} = 80 Vdc, I _B = 0)	2N6667 2N6668	I _{CEO}	— —	1 1	mAdc
Collector Cutoff Current (V _{CE} = 60 Vdc, V _{EB(off)} ≈ 1.5 Vdc) (V _{CE} = 80 Vdc, V _{EB(off)} ≈ 1.5 Vdc) (V _{CE} = 60 Vdc, V _{EB(off)} ≈ 1.5 Vdc, T _C = 125°C) (V _{CE} = 80 Vdc, V _{EB(off)} ≈ 1.5 Vdc, T _C = 125°C)	2N6667 2N6668 2N6667 2N6668	I _{CEX}	— — — —	300 300 3 3	μAdc mAdc
Emitter Cutoff Current (V _{BE} = 5 Vdc, I _C = 0)		I _{EBO}	—	5	mAdc

ON CHARACTERISTICS (1)

DC Current Gain (I _C = 5 Adc, V _{CE} = 3 Vdc) (I _C = 10 Adc, V _{CE} = 3 Vdc)	h _{FE}	1000 100	20000 —	—
Collector-Emitter Saturation Voltage (I _C = 5 Adc, I _B = 0.01 Adc) (I _C = 10 Adc, I _B = 0.1 Adc)	V _{CE(sat)}	— —	2 3	Vdc
Base-Emitter Saturation Voltage (I _C = 5 Adc, I _B = 0.01 Adc) (I _C = 10 Adc, I _B = 0.1 Adc)	V _{BE(sat)}	— —	2.8 4.5	Vdc

DYNAMIC CHARACTERISTICS

Small-Signal Current Gain (I _C = 1 Adc, V _{CE} = 5 Vdc, f _{test} = 1 MHz)	h _{fe}	20	—	—
Output Capacitance (V _{CB} = 10 Vdc, I _E = 0, f = 1 MHz)	C _{ob}	—	200	pF
Small-Signal Current Gain (I _C = 1 Adc, V _{CE} = 5 Vdc, f = 1 kHz)	h _{fe}	1000	—	—

* Indicates JEDEC Registered Data

(1) Pulse Test: Pulse Width ≤ 300 μs, Duty Cycle ≤ 2%.

R_B & R_C VARIED TO OBTAIN DESIRED CURRENT LEVELS
D₁ MUST BE FAST RECOVERY TYPES, e.g.,
MBD5300 USED ABOVE I_B ≈ 100 mA
MSD6100 USED BELOW I_B ≈ 100 mA

FOR t_d AND t_r, D₁ IS DISCONNECTED AND V₂ = 0
t_r, t_f ≤ 10 ns
DUTY CYCLE = 1%

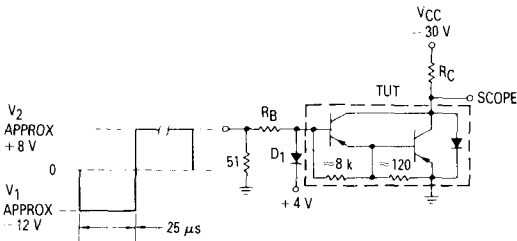


Figure 2. Switching Times Test Circuit

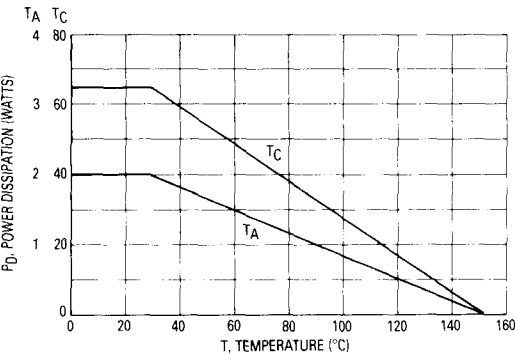


Figure 3. Power Derating

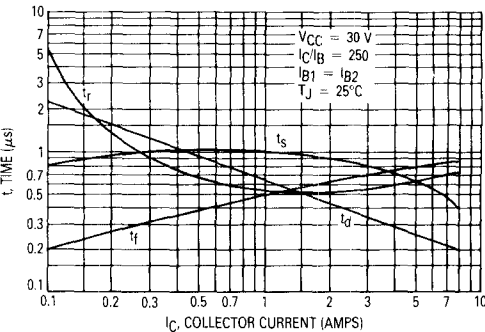


Figure 4. Typical Switching Times

2N6667, 2N6668

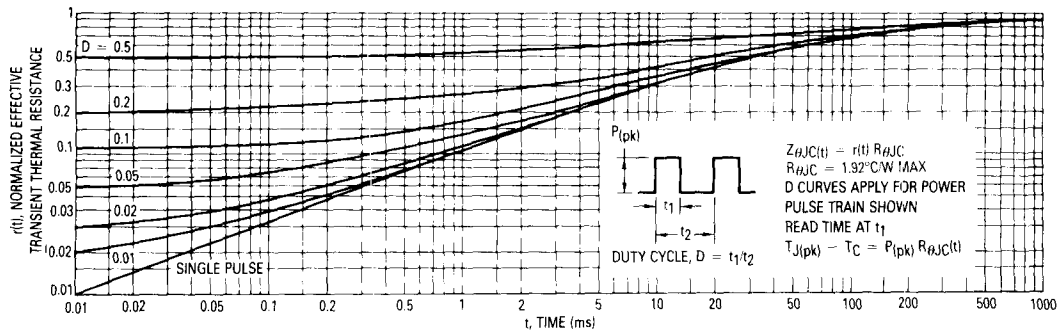


Figure 5. Thermal Response

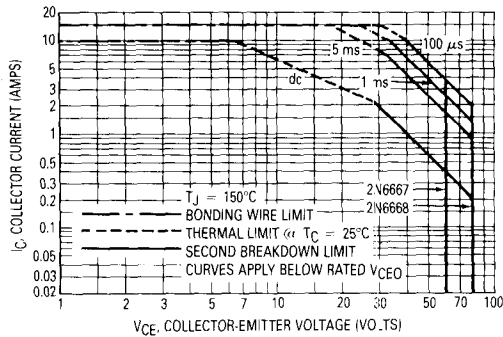


Figure 6. Maximum Safe Operating Area

There are two limitations on the power handling ability of a transistor: average junction temperature and second breakdown. Safe operating area curves indicate I_C - V_{CE} limits of the transistor that must be observed for reliable operation; i.e., the transistor must not be subjected to greater dissipation than the curves indicate.

The data of Figure 6 is based on $T_J(pk) = 150^\circ\text{C}$; T_C is variable depending on conditions. Second breakdown pulse limits are valid for duty cycles to 10% provided $T_J(pk) < 150^\circ\text{C}$. $T_J(pk)$ may be calculated from the data in Figure 5. At high case temperatures, thermal limitations will reduce the power that can be handled to values less than the limitations imposed by second breakdown.

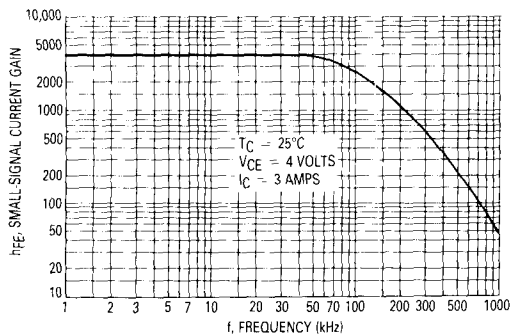


Figure 7. Typical Small-Signal Current Gain

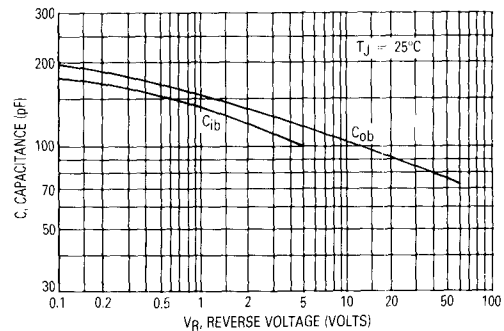


Figure 8. Typical Capacitance

2N6667, 2N6668

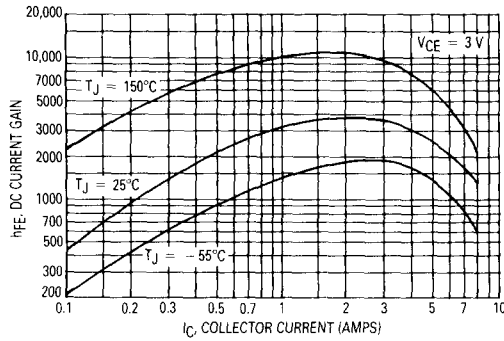


Figure 9. Typical DC Current Gain

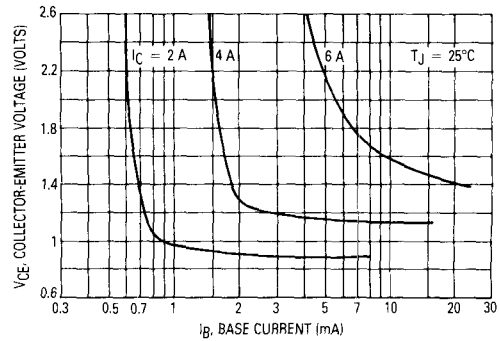


Figure 10. Typical Collector Saturation Region

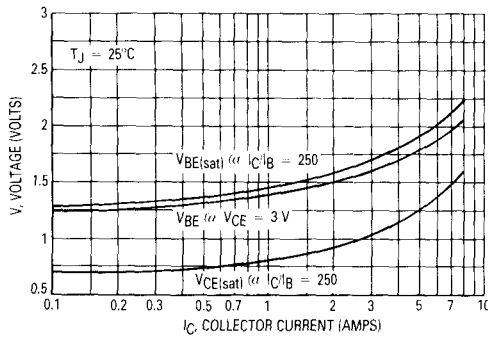


Figure 11. Typical "On" Voltages

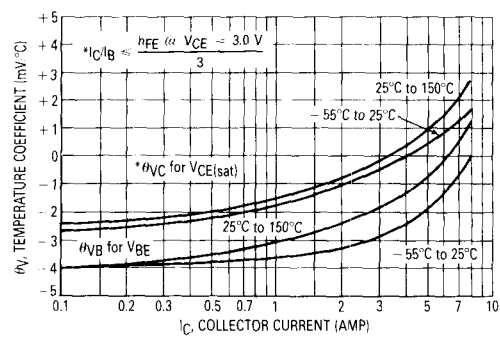


Figure 12. Typical Temperature Coefficients

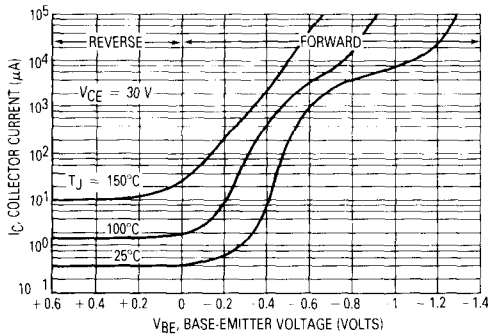


Figure 13. Typical Collector Cut-Off Region

